

Preliminary TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

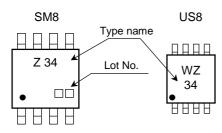
# TC7WZ34FU,TC7WZ34FK

#### Triple Non Inverter

#### **Features**

- High output drive:  $\pm 24$  mA (min) @V<sub>CC</sub> = 3 V
- Super high speed operation:  $t_{pd}$  2.4 ns (typ.) @VCC = 5 V,
- Operation voltage range:  $V_{CC\ (opr)} = 1.65 \sim 5.5\ V$
- Latch-up performance: ±500 mA or more
- ESD performance: ±200 V or more (JEITA) ±2000 V or more (MIL)
- Power down protection is provided on all inputs and outputs.
- Matches the performance of TC74LCX series when operated at 3.3 V VCC.

#### Marking



# TC7WZ34FU SSOP8-P-0.65 TC7WZ34FK SSOP8-P-0.50A

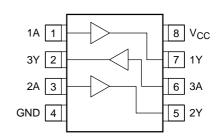
Weight

SSOP8-P-0.65 : 0.02 g (typ.) SSOP8-P-0.50A : 0.01 g (typ.)

#### **Maximum Ratings (Ta = 25°C)**

Characteristics	Symbol	Rating	Unit	
Power supply voltage	Vcc	-0.5~6	V	
DC input voltage	V <sub>IN</sub>	-0.5~6	V	
DC output voltage	Vout	-0.5~6	V	
Input diode current	I <sub>IK</sub>	-20	mA	
Output diode current	lok	-20	mA	
DC output current	lout	±50	mA	
DC V <sub>CC</sub> /ground current	Icc	±50	mA	
Power dissipation	P <sub>D</sub>	300 (SM8) 200 (US8)	mW	
Storage temperature	T <sub>stg</sub>	-65~150	°C	
Lead temperature (10s)	TL	260	°C	

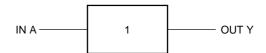
## Pin Assignment (top view)



#### **Truth Table**

А	Υ
L	L
Н	Н

# **Logic Diagram**



# **Recommended Operating Conditions**

Characteristics	Symbol	Rating	Unit	
Supply voltage	V <sub>CC</sub>	1.65~5.5	V	
Supply voltage	vCC	1.5~5.5 (Note 1)	v	
Input voltage	V <sub>IN</sub>	0~5.5	V	
Output voltage	V <sub>OUT</sub>	0~5.5 (Note 2)	V	
		0~V <sub>CC</sub> (Note 3)	v	
Operating temperature	T <sub>opr</sub>	-40~85	°C	
	$d_{t}/d_{V}$	$0 \sim 20 \; (V_{CC} = 1.8 \; V \pm 0.15 \; V, \\ 2.5 \; V \pm 0.2 \; V)$	ns/V	
Input rise and fall time		$0 \sim 10 \; (V_{CC} = 3.3 \; V \pm 0.3 \; V)$		
		$0~5~(V_{CC} = 5.5~V \pm 0.5~V)$		

Note 1: Data retention only

Note 2:  $V_{CC} = 0 V$ 

Note 3: High or low state



# **Electrical Characteristics**

# **DC Characteristics**

Characteristics		Cumbal	Symbol Test Condition			Ta = 25°C			Ta = -40~85°C		Lloit
		Symbol	rest	Test Condition		Min	Тур.	Max	Min	Max	Unit
Input voltage  Low level	High lovel	V			1.65~ 1.95	0.75 × V <sub>CC</sub>	_	_	0.75 × V <sub>CC</sub>	_	
	V <sub>IH</sub>		_		0.7 × V <sub>CC</sub>	_	_	0.7 × V <sub>CC</sub>	_	V	
				1.65~ 1.95	_	_	0.25 × V <sub>CC</sub>	_	0.25 × V <sub>CC</sub>		
	Low level	V <sub>IL</sub>			2.3~5.5	_	_	0.3 × V <sub>CC</sub>		0.3 × V <sub>CC</sub>	
					1.65	1.55	1.65	_	1.55	_	
				I <sub>OH</sub> = -100 μA	2.3	2.2	2.3	—	2.2	_	
				10Η = -100 μΛ	3.0	2.9	3.0	_	2.9	_	
					4.5	4.4	4.5	_	4.4	_	
	High level	VoH	$V_{IN} = V_{IH}$	$I_{OH} = -4 \text{ mA}$	1.65	1.29	1.52	_	1.29	_	V
				$I_{OH} = -8 \text{ mA}$	2.3	1.9	2.14	_	1.9	_	
				I <sub>OH</sub> = -16 mA	3.0	2.4	2.75	_	2.4	_	
				I <sub>OH</sub> = -24 mA	3.0	2.3	2.62	_	2.3	_	
Output				I <sub>OH</sub> = -32 mA	4.5	3.8	4.13	_	3.8	_	
voltage			$V_{IN} = V_{IL}$	I <sub>OL</sub> = 100 μA	1.65	_	0	0.1	_	0.1	
					2.3	_	0	0.1	_	0.1	
					3.0	_	0	0.1		0.1	
					4.5	_	0	0.1	_	0.1	
	Low level	V <sub>OL</sub>		I <sub>OL</sub> = 4 mA	1.65	_	0.08	0.24	_	0.24	
				I <sub>OL</sub> = 8 mA	2.3	_	0.1	0.3		0.3	
				I <sub>OL</sub> = 16 mA	3.0	_	0.16	0.4		0.4	
				I <sub>OL</sub> = 24 mA	3.0	_	0.24	0.55		0.55	
				I <sub>OL</sub> = 32 mA	4.5	_	0.25	0.55	_	0.55	
Input leakage current I <sub>IN</sub> V <sub>IN</sub> = 5.5 V or GND		0~5.5		_	±1		±10	μА			
Power off leakage current   I <sub>OFF</sub>   V <sub>IN</sub>		V <sub>IN</sub> or V <sub>OL</sub>	V <sub>IN</sub> or V <sub>OUT</sub> = 5.5 V		_		1		10	μΑ	
Quiescent supply current		Icc	V <sub>IN</sub> = 5.5 \	or GND	1.65~5.5	_		1		10	μА

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# AC Characteristics (unless otherwise specified, Input: $t_r = t_f = 3$ ns)

Characteristics	Cumbal	Test Condition		Ta = 25°C			Ta = -40~85°C		Lloit
Characteristics	Symbol	rest Condition	V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	Unit
Propagation delay time	<sup>t</sup> pLH <sup>t</sup> pHL	$C_L = 15 \text{ pF}, R_L = 1 \text{ M}\Omega$	$1.8 \pm 0.15$	2.0	4.4	9.5	2.0	10.0	- ns
			$2.5\pm0.2$	1.0	3.0	5.2	1.0	5.8	
			$3.3 \pm 0.3$	0.8	2.3	3.6	0.8	4.0	
			$5.0 \pm 0.5$	0.5	1.8	2.9	0.5	3.2	
		$C_L = 50 \text{ pF}, R_L = 500 \Omega$	$3.3 \pm 0.3$	1.2	3.0	4.6	1.2	5.1	
			$5.0 \pm 0.5$	0.8	2.4	3.8	0.8	4.2	
Input capacitance	C <sub>IN</sub>	_	0~5.5	_	3.0	_	_	_	pF
Power dissipation capacitance	C <sub>PD</sub>	(Note)	3.3	_	24	_	_	_	pF
			5.5	_	34	_	_	_	PF

Note: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

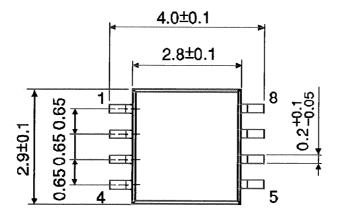
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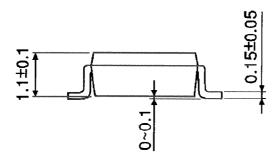
Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/3$ 

# **Package Dimensions**

SSOP8-P-0.65 Unit: mm

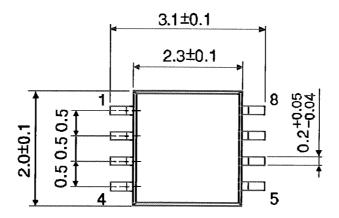


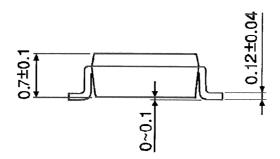


Weight: 0.02 g (typ.)

# **Package Dimensions**

SSOP8-P-0.50A Unit: mm





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Weight: 0.01 g (typ.)

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